High Isolation Gate Drive Transformers

PH9400.XXXNL and PH9400.XXXANL - SMT









Basic and Reinforced Insulation

🜈 Sidecar package with 12mm creepage

Up to 5000Vrms gate to drive isolation

1000Vrms continuous isolation between windings

Up to 8W of Driver Power

Patented: US Patent 9,646,755

Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C										
Part	Turns Ratio	(1-4) (V * µsec MAX)	Core Loss Factor K1	Primary Inductance (1-4) (mH +/-35%)	Leakage Inductance Drive to Gate (µH MAX)	Parasitic Capacitance Drive to Gate (pF MAX)	DCR Drive (1-4) (Ω MAX)	DCR Gates (5-6) (7-8) (Ω MAX)	Hi-Pot	
Number									Drive-Gate (Vrms)	Gate-Gate (Vrms)
PH9400.XXXNL - Basic Insulation 600Vrms continuous isolation										
PH9400.111NL	1:1:1	315	0.67	4.5	5.0	60	1.8	2.5	4000	1500
PH9400.566NL	5:6:6	315	0.67	4.5	3.5	60	1.8	3.0	4000	1500
PH9400.122NL	1:2:2	250	0.84	2.88	3.5	60	1.5	4.2	4000	1500
PH9400.655NL	6:5:5	375	0.56	6.48	5.3	60	2.2	2.5	4000	1500
PH9400.211NL	2:1:1	375	0.56	6.48	8.0	60	2.2	1.6	4000	1500
PH9400.XXXANL - Reinforced Insulation 1000Vrms continuous isolation										
PH9400.111ANL	1:1:1	160	1.32	1.21	2.5	45	0.9	0.9	5000	2000
PH9400.566ANL	5:6:6	155	1.36	1.12	3.0	45	0.9	1.0	5000	2000
PH9400.233ANL	2:3:3	125	1.68	0.72	2.0	45	0.7	1.0	5000	2000
PH9400.655ANL	6:5:5	185	1.14	1.62	3.0	45	1.0	0.9	5000	2000
PH9400.211ANL	2:1:1	185	1.14	1.62	3.5	45	1.0	0.55	5000	2000

Notes:

- The max ET is calculated to limit the core loss and temperature rise at 100KHz based on a bipolar flux swing of 2100Ga Peak. This value needs to be derated for higher frequencies using the temperature rise calculation.
- The temperature rise of the component is calculated based on the total core loss and copper loss:
 - A. To calculate total copper loss (W), use the following formula:

 Copper Loss (W) = Irms² * (DCR_Drive + (# of Gates) * DCR_Gates)
 - B. To calculate total core loss (W), use the following formula:

 Core Loss (W) = 5.1E-10 * (Frequency in kHz)^{1,42} * (K1 * ET)^{2,5}

 Where ET = (V * Duty Cycle) / Frequency
 - C. To calculate temperature rise, use the following formula: Temperature Rise (°C) = 71 * (Core Loss(W) + Copper Loss (W))
- Continuous isolation voltage confirmed by 125°C/1000hrs accelerated aging with the bias voltage applied between gate and drive windings.

- ANL versions, which use triple insulated wire on both the drive and gate windings, are compliant with IEC 60950, IEC 61558, IEC 61010 & IEC 60601 for reinforced insulation.
 - NL versions, which use triple insulated wire on just the drive winding, comply with basic insulation requirements.
- 12mm package creepage distance satisfies IEC60950-1 & IEC61558-1/-2-16 reinforced insulation requirements for working voltage to 600Vrms max, OVC II, Pollution Degree 2 and altitude up to 2000m.
- 6. Unless otherwise specified, all testing is made at 100kHz, 0.1VAC.
- Optional Tape & Reel packaging can be ordered by adding a "T" suffix to the part number (i.e. PH9400.111NL becomes PH9400.111NLT). Pulse complies to industry standard tape and reel specification EIA481.

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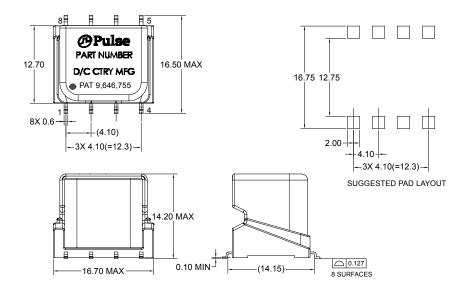
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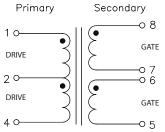
Mechanicals

Schematics

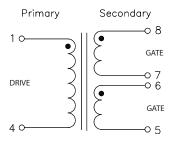
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PH9400.XXXANL



Weight	2.5 grams
Tape & Reel	-
Trav	80/trav

Dimension: Inches

Unless otherwise specified, all tolerances are $\pm \frac{.010}{0.25}$

For More Information:

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